

Micropower, Rail-to-Rail Input Current Sense Amplifier with Voltage Output

ISL28005

The ISL28005 is a micropower, uni-directional high-side and low-side current sense amplifier featuring a proprietary rail-to-rail input current sensing amplifier. The ISL28005 is ideal for high-side current sense applications where the sense voltage is usually much higher than the amplifier supply voltage. The device can be used to sense voltages as high as 28V when operating from a supply voltage as low as 2.7V. The micropower ISL28005 consumes only $50\mu A$ of supply current when operating from a 2.7V to 28V supply.

The ISL28005 features a common-mode input voltage range from 0V to 28V. The proprietary architecture extends the input voltage sensing range down to 0V, making it an excellent choice for low-side ground sensing applications. The benefit of this architecture is that a high degree of total output accuracy is maintained over the entire 0V to 28V common mode input voltage range.

The ISL28005 is available in fixed (100V/V, 50V/V and 20V/V) gains in the space saving 5 Ld SOT-23 package. The parts operate over the extended temperature range from -40°C to +125°C.

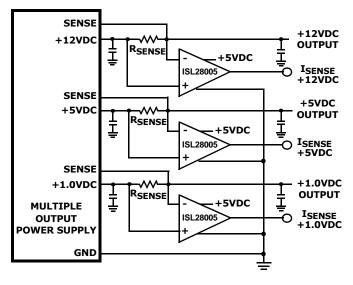
Features

• Low Power Consumption 50μA,Typ
• Supply Range 2.7V to 28V
• Wide Common Mode Input 0V to 28V
Fixed Gain Versions
- ISL28005-100100V/V
- ISL28005-5050V/V
- ISL28005-2020V/V
• Operating Temperature Range40°C to +125°C
• Package

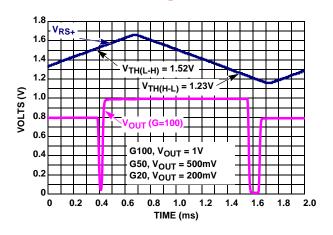
Applications*(see page 13)

- Power Management/Monitors
- Power Distribution and Safety
- DC/DC, AC/DC Converters
- Battery Management /Charging
- Automotive Power Distribution

Typical Application

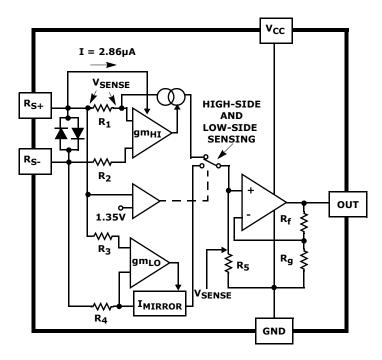


High-Side And Low-Side Threshold Voltage

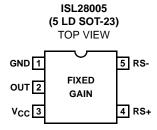


1

Block Diagram



Pin Configuration



Pin Descriptions

ISL28005 (5 LD SOT-23)	PIN NAME	DESCRIPTION
1	GND	Power Ground
2	OUT	Amplifier Output
3	V _{CC}	Positive Power Supply
4	RS+	Sense Voltage Non-inverting Input
5	RS-	Sense Voltage Inverting Input
RS- D	5	CAPACITIVELY COUPLED ESD CLAMP

Ordering Information

PART NUMBER (Notes 1, 2, 3)	GAIN	PART MARKING	PACKAGE Tape & Reel (Pb-Free)	PKG. DWG. #
ISL28005FH100Z-T7	100V/V	BDEA	5 Ld SOT-23	MDP0038
ISL28005FH50Z-T7	50V/V	BDDA	5 Ld SOT-23	MDP0038
ISL28005FH20Z-T7	20V/V	BDCA	5 Ld SOT-23	MDP0038

NOTES:

- 1. Please refer to $\underline{\mathsf{TB347}}$ for details on reel specifications.
- 2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- 3. For Moisture Sensitivity Level (MSL), please see device information page for <u>ISL28005</u>. For more information on MSL please see techbrief <u>TB363</u>.

ISL28005

Absolute Maximum Ratings

Max Supply Voltage	3V
Max Differential Input Current20m	nΑ
Max Differential Input Voltage	5V
Max Input Voltage (RS+, RS-) GND-0.5V to 30	VC
Max Input Current for Input Voltage <gnd -0.5v="" td="" ±20m<=""><td></td></gnd>	
Output Short-Circuit Duration Indefini	te
ESD Rating	
Human Body Model 4	ĸ۷
Machine Model200	VC
Charged Device Model1.5k	۲V

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
5 Ld SOT-23 (Notes 4, 5)	. 190	90
Maximum Storage Temperature Rang	je65°	C to +150°C
Maximum Junction Temperature (T _{JM}	_{IAX})	+150°C
Pb-Free Reflow Profile		ee link below
http://www.intersil.com/pbfree/Pb-	-FreeReflow.	<u>asp</u>

Recommended Operating Conditions

Ambient Temperature Range(T_A) -40°C to +125°C

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- 4. θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- 5. For $\theta J C$, the "case temp" location is taken at the package top center.

Electrical Specifications $V_{CC} = 12V$, $V_{RS+} = 0V$ to 28V, $V_{SENSE} = 0V$, $R_{LOAD} = 1M\Omega$, $T_A = +25^{\circ}C$ unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +125°C. Temperature data established by characterization.

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 6)	TYP	MAX (Note 6)	UNIT
Vos	Input Offset Voltage (Notes 7, 8)	V _{CC} = V _{RS} + = 12V, V _S = 20mV to = 100mV	-500 -500	60	500 500	μV
		$V_{CC} = 12V$, $V_{RS} + = 0.2V$, $V_{S} = 20$ mV, $V_{S} = 100$ mV	-3 -3.3	-1.2	3 3.3	mV
I _{RS} +, I _{RS} -	Leakage Current	V _{CC} = 0V, V _{RS+} = 28V		0.041	1.2 1.5	μA
I _{RS} +	Gain = 100 + Input Bias Current	V_{RS} + = 2V, V_{SENSE} = 5mV		4.7	6 7	μA
		V _{RS} + = 0V, V _{SENSE} = 5mV	-500 -600	-425		nA
	Gain = 50, Gain = 20 +Input Bias Current	V_{RS} + = 2V, V_{SENSE} = 5mV		4.7	6 8	μA
		V _{RS} + = 0V, V _{SENSE} = 5mV	-700 -840	-432		nA
I _{RS} -	Input Bias Current	V _{RS} + = 2V, V _{SENSE} = 5mV		5	50 75	nA
		V _{RS} + = 0V, V _{SENSE} = 5mV	-125 -130	-45		nA
CMRR	Common Mode Rejection Ratio	V _{RS} + = 2V to 28V	105	115		dB
PSRR	Power Supply Rejection Ratio	$V_{CC} = 2.7V \text{ to } 28V, V_{RS} + = 2V$	90	105		dB
VFS	Full-scale Sense Voltage	V _{CC} = 28V, V _{RS} + = 0.2V, 12V	200			mV
G	Gain	ISL28005-100		100		V/V
	(Note 7)	ISL28005-50		50		V/V
		ISL28005-20		20		V/V

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 6)	TYP	MAX (Note 6)	UNIT
G _A	Gain = 100 Gain Accuracy (Note 9)	V _{CC} = V _{RS} + = 12V, V _{SENSE} = 20mV to 100mV	-2 - 3		2 3	%
		V _{CC} = 12V, V _{RS} + = 0.1V, V _{SENSE} = 20mV to 100mV		-0.25		%
	Gain = 50, Gain = 20 Gain Accuracy (Note 9)	V _{CC} = V _{RS} + = 12V, V _{SENSE} = 20mV to 100mV	-2 -3		2 3	%
		V _{CC} = 12V, V _{RS} + = 0.1V, V _{SENSE} = 20mV to 100mV	-3 -4	-0.31	3 4	%
V _{OA}	Gain = 100 Total Output Accuracy (Note 10)	V _{CC} = V _{RS} + = 12V, V _{SENSE} = 100mV	-2.5 -2.7		2.5 2.7	%
		V _{CC} = 12V, V _{RS} + = 0.1V, V _{SENSE} = 100mV		-1.25		%
	Gain = 50, Gain = 20 Total Output Accuracy (Note 10)	V _{CC} = V _{RS} + = 12V, V _{SENSE} = 100mV	-2.5 -2.7		2.5 2.7	%
		V _{CC} = 12V, V _{RS} + = 0.1V, V _{SENSE} = 100mV	-6 -7	-1.41	6 7	%
V _{OH}	Output Voltage Swing, High VCC - VOUT	$I_{O} = -500 \mu A$, $V_{CC} = 2.7 V$ $V_{SENSE} = 100 mV$ $V_{RS} + = 2 V$		39	50	mV
V _{OL}	Output Voltage Swing, Low Vout	I _O = 500μA, V _{CC} = 2.7V V _{SENSE} = 0V, V _{RS} + = 2V		30	50	mV
R _{OUT}	Output Resistance	$V_{CC} = V_{RS} + = 12V,$ $V_{SENSE} = 100$ mV $I_{OUT} = 10$ µA to 1mA		6.5		Ω
I _{SC+}	Short Circuit Sourcing Current	$V_{CC} = V_{RS} + = 5V$, $R_L = 10\Omega$		4.8		mA
I _{SC} -	Short Circuit Sinking Current	$V_{CC} = V_{RS} + = 5V$, $R_L = 10\Omega$		8.7		mA
I _S	Gain = 100 Supply Current	V _{RS} + > 2V, V _{SENSE} = 5mV		50	59 62	μΑ
	Gain = 50, 20 Supply Current	V _{RS} + > 2V, V _{SENSE} = 5mV		50	62 63	μΑ
V _{CC}	Supply Voltage	Guaranteed by PSRR	2.7		28	V
SR	Gain = 100 Slew Rate	Pulse on RS+ pin, $V_{OUT} = 8V_{P-P}$ (see Figure 15)	0.58	0.76		V/µs
	Gain = 50 Slew Rate	Pulse on RS+ pin, $V_{OUT} = 8V_{P-P}$ (see Figure 15)	0.58	0.67		V/µs
	Gain = 20 Slew Rate	Pulse on RS+ pin, V _{OUT} = 3.5V _{P-P} (see Figure 15)	0.50	0.67		V/µs
BW _{-3dB}	Gain = 100 -3dB Bandwidth	V _{RS} + = 12V, 0.1V, V _{SENSE} = 100mV		110		kHz
	Gain = 50 -3dB Bandwidth	V _{RS} + = 12V, 0.1V, V _{SENSE} = 100mV		160		kHz
	Gain = 20 -3dB Bandwidth	V _{RS} + = 12V, 0.1V, V _{SENSE} = 100mV		180		kHz

Electrical Specifications $V_{CC} = 12V$, $V_{RS+} = 0V$ to 28V, $V_{SENSE} = 0V$, $R_{LOAD} = 1M\Omega$, $T_A = +25^{\circ}C$ unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +125°C. Temperature data established by characterization. (Continued)

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 6)	TYP	MAX (Note 6)	UNIT
t _s	Output Settling Time to 1% of Final Value	$V_{CC} = V_{RS} + = 12V$, $V_{OUT} = 10V$ step, $V_{SENSE} > 7mV$		15		μs
		$V_{CC} = V_{RS} + = 0.2V$, $V_{OUT} = 10V$ step, $V_{SENSE} > 7mV$		20		μs
	Capacitive-Load Stability	No sustained oscillations		300		pF
t _{s Power-up}	Power-Up Time to 1% of Final Value	$V_{CC} = V_{RS} + = 12V,$ $V_{SENSE} = 100mV$		15		μs
		$V_{CC} = 12V$, $V_{RS} + = 0.2V$ $V_{SENSE} = 100$ mV		50		μs
	Saturation Recovery Time	$V_{CC} = V_{RS} + = 12V,$ $V_{SENSE} = 100$ mV, overdrive		10		μs

NOTES:

- 6. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.
- 7. DEFINITION OF TERMS:
 - V_{SENSE}A = V_{SENSE} @100mV
 - V_{SENSE}B = V_{SENSE} @20mV
 - V_{OUT}A = V_{OUT}@V_{SENSE}A=100mV
 - $V_{OUT}B = V_{OUT}@V_{SENSE}B = 20mV$

$$\bullet \ G = GAIN = \left(\frac{V_{OUT}A - V_{OUT}B}{V_{SENSE}A - V_{SENSE}B} \right)$$

- 8. V_{OS} is extrapolated from the gain measurement. $V_{OS} = V_{SENSE}A \frac{V_{OUT}A}{G}$
- 9. % Gain Accuracy = $G_A = \left(\frac{G_{MEASURED} G_{EXPECTED}}{G_{EXPECTED}}\right) \times 100$
- 10. Output Accuracy % $V_{OA} = \left(\frac{VOUT_{MEASURED} VOUT_{EXPECTED}}{VOUT_{EXPECTED}}\right) \times 100$ where $V_{OUT} = V_{SENSE} \times GAIN$ and $V_{SENSE} = 100 \text{mV}$

Typical Performance Curves V_{cc} = 12V, R_L = 1M, unless otherwise specified.

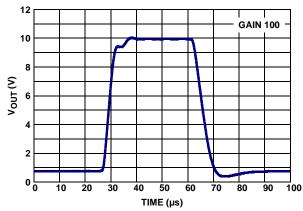


FIGURE 1. LARGE SIGNAL TRANSIENT RESPONSE $V_{RS+} = 0.2V, \, V_{SENSE} = 100 \text{mV}$

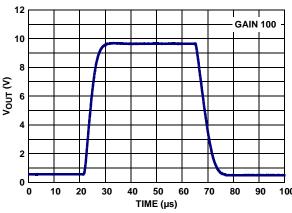


FIGURE 2. LARGE SIGNAL TRANSIENT RESPONSE $V_{RS+} = 12V$, $V_{SENSE} = 100$ mV

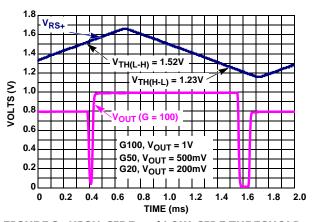


FIGURE 3. HIGH-SIDE and LOW-SIDE THRESHOLD VOLTAGE $V_{RS+(L-H)}$ and $V_{RS+(H-L)}$, $V_{SENSE} = 10 \text{mV}$

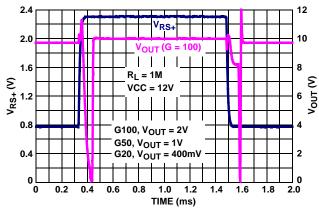


FIGURE 4. V_{OUT} vs V_{RS+} , $V_{SENSE} = 20$ mV TRANSIENT RESPONSE

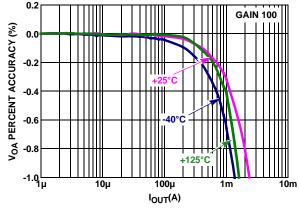


FIGURE 5. NORMALIZED V_{OA} vs I_{OUT}

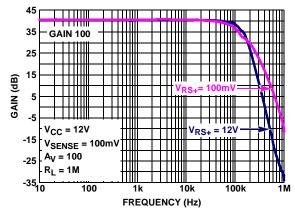


FIGURE 6. GAIN vs FREQUENCY V_{RS+} = 100mV/12V, V_{SENSE} = 100mV, V_{OUT} = 250mV_{P-P}

Typical Performance Curves $V_{cc} = 12V$, $R_L = 1M$, unless otherwise specified. (Continued)

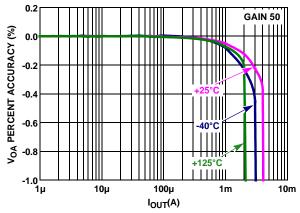


FIGURE 7. NORMALIZED V_{OA} vs I_{OUT}

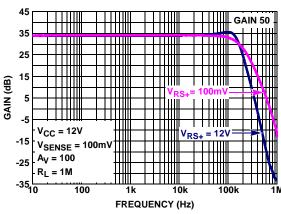


FIGURE 8. GAIN vs FREQUENCY $V_{RS+}=100mV/12V$, $V_{SENSE}=100mV$, $V_{OUT}=250mV_{P-P}$

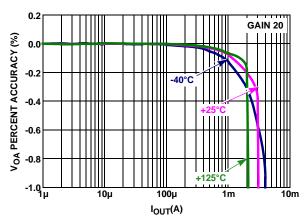


FIGURE 9. NORMALIZED V_{OA} vs I_{OUT}

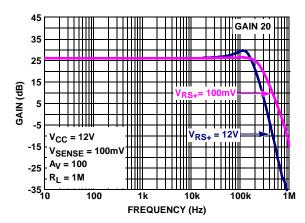


FIGURE 10. GAIN vs FREQUENCY V_{RS+} =100mV/12V, V_{SENSE} = 100mV, V_{OUT} = 250mV_{P-P}

Test Circuits and Waveforms

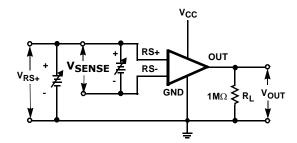


FIGURE 11. $I_{S_r} V_{OS_r} V_{OA_r}$ CMRR, PSRR, GAIN ACCURACY

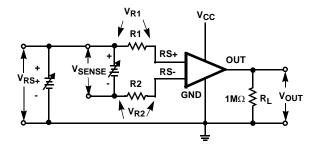


FIGURE 12. INPUT BIAS CURRENT, LEAKAGE CURRENT

Test Circuits and Waveforms (Continued)

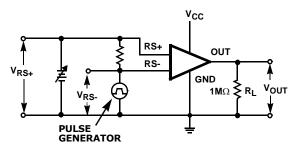


FIGURE 13. SLEW RATE, t_s , SATURATION RECOVERY TIME

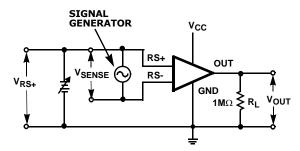


FIGURE 14. GAIN vs FREQUENCY

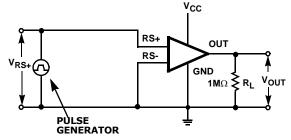


FIGURE 15. SLEW RATE

Applications Information

Functional Description

The ISL28005-20, ISL28005-50 and ISL28005-100 are single supply, uni-directional current sense amplifiers with fixed gains of 20V/V, 50V/V and 100V/V respectively.

The ISL28005 is a 2-stage amplifier. Figure 16 shows the active circuitry for high-side current sense applications where the sense voltage is between 1.35V to 28V. Figure 17 shows the active circuitry for ground sense applications where the sense voltage is between 0V to 1.35V.

The first stage is a bi-level trans-conductance amp and level translator. The gm stage converts the low voltage drop (V_{SENSE}) sensed across an external milli-ohm sense resistor, to a current (@ gm = 21.3μ A/V). The trans-conductance amplifier forces a current through R₁ resulting to a voltage drop across R₁ that is equal to the

sense voltage (V_{SENSE}). The current through R_1 is mirrored across R_5 creating a ground-referenced voltage at the input of the second amplifier equal to V_{SENSE} .

The second stage is responsible for the overall gain and frequency response performance of the device. The fixed gains (20, 50, 100) are set with internal resistors R_f and R_g . The only external component needed is a current sense resistor (typically 0.001Ω to 0.01Ω , 1W to 2W).

The transfer function is given in Equation 1.

$$V_{OUT} = GAIN \times (I_S R_S + V_{OS})$$
 (EQ. 1)

The input gm stage derives its ~2.86µA supply current from the input source through the RS+ terminal as long as the sensed voltage at the RS+ pin is >1.35V and the gm_HI amplifier is selected. When the sense voltage at RS+ drops below the 1.35V threshold, the gm_LO amplifier kicks in and the gm_LO output current reverses, flowing out of the RS- pin.

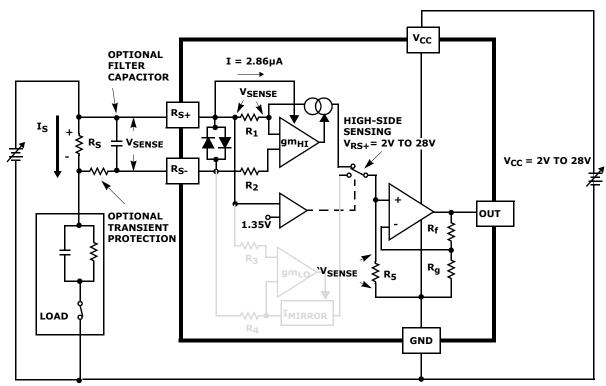


FIGURE 16. HIGH-SIDE CURRENT DETECTION

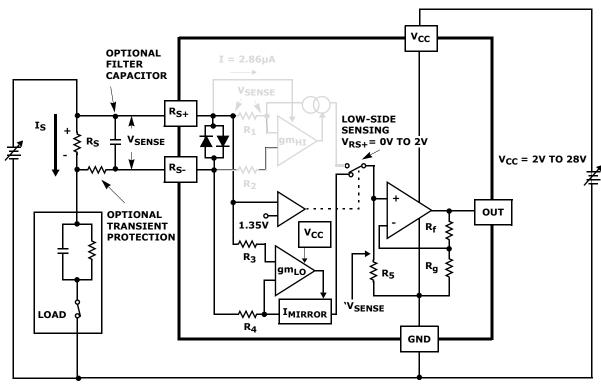


FIGURE 17. LOW-SIDE CURRENT DETECTION

Hysteretic Comparator

The input trans-conductance amps are under control of a hysteretic comparator operating from the incoming source voltage on the RS+ pin (see Figure 18). The comparator monitors the voltage on RS+ and switches the sense amplifier from the low-side gm amp to the high-side gm amplifier whenever the input voltage at RS+ increases above the 1.35V threshold. Conversely, a decreasing voltage on the RS+ pin, causes the hysteric comparator to switch from the high-side gm amp to the low-side gm amp as the voltage decreases below 1.35V. It is that low-side sense gm amplifier that gives the ISL28005 the proprietary ability to sense current all the way to 0V. Negative voltages on the RS+ or RS- are beyond the sensing voltage range of this amplifier.

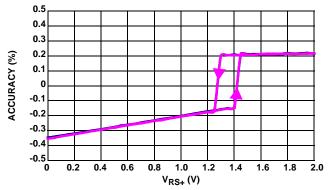


FIGURE 18. GAIN ACCURACY vs $V_{RS+} = 0V TO 2V$

Typical Application Circuit

Figure 20 shows the basic application circuit and optional protection components for switched-load applications. For applications where the load and the power source is permanently connected, only an external sense resistor is needed. For applications where fast transients are caused by hot plugging the source or load, external protection components may be needed. The external current limiting resistor (Rp) in Figure 20 may be required to limit the peak current through the internal ESD diodes to < 20mA. This condition can occur in applications that experience high levels of in-rush current causing high peak voltages that can damage the internal ESD diodes. An Rp resistor value of 100Ω will provide protection for a 2V transient with the maximum of 20mA

flowing through the input while adding only an additional $13\mu V$ (worse case over-temperature) of V_{OS} . Refer to the following formula:

$$((R_P \times I_{RS-}) = (100\Omega \times 130 \text{nA}) = 13 \mu\text{V})$$

Switching applications can generate voltage spikes that can overdrive the amplifier input and drive the output of the amplifier into the rails, resulting in a long overload recovery time. Capacitors C_M and C_D filter the common mode and differential voltage spikes.

Error Sources

There are 3 dominant error sources: gain error, input offset voltage error and Kelvin voltage error (see Figure 19). The gain error is dominated by the internal resistance matching tolerances. The remaining errors appear as sense voltage errors at the input to the amplifier. They are V_{OS} of the amplifier and Kelvin voltage errors. If the transient protection resistor is added, an additional V_{OS} error can result from the IxR voltage due to input bias current. The limiting resistor should only be added to the R_{S^-} input, due to the high-side gm amplifier (gm $_{HI}$) sinking several micro amps of current through the RS+ pin.

Layout Guidelines

Kelvin Connected Sense Resistor

The source of Kelvin voltage errors is illustrated in Figure 19. The resistance of 1/2 oz. copper is $\sim 1 \text{m}\Omega$ per square with a TC of ~3900ppm/°C (0.39%/°C). When you compare this unwanted parasitic resistance with the total of $1m\Omega$ to $10m\Omega$ resistance of the sense resistor, it is easy to see why the sense connection must be chosen very carefully. For example, consider a maximum current of 20A through a 0.005Ω sense resistor, generating a $V_{SENSE} = 0.1$ and a full scale output voltage of 10V (G = 100). Two side contacts of only 0.25 square per contact puts the V_{SENSE} input about 0.5 x $1m\Omega$ away from the resistor end capacitor. If only 10A the 20A total current flows through the kelvin path to the resistor, you get an error voltage of 10mV (10A x 0.5sg x $0.001\Omega/sg$. = 10mV) added to the 100mV sense voltage for a sense voltage error of 10% (0.110V - 0.1)/0.1V)x 100.

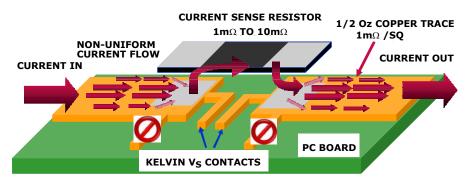


FIGURE 19. PC BOARD CURRENT SENSE KELVIN CONNECTION

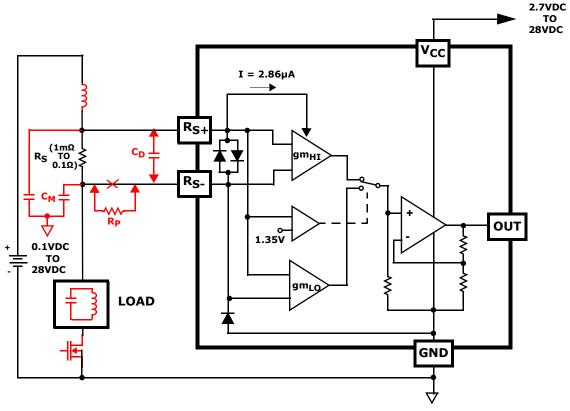


FIGURE 20. TYPICAL APPLICATION CIRCUIT

Overall Accuracy (VOA %)

 $V_{\mbox{\scriptsize OA}}$ is defined as the total output accuracy Referred-to-Output (RTO). The output accuracy contains all offset and gain errors, at a single output voltage. Equation 2 is used to calculate the % total output accuracy.

$$V_{OA} = 100 \times \left(\frac{V_{OUT} actual - V_{OUT} expected}{V_{OUT} expected} \right)$$
 (EQ. 2)

where

 V_{OUT} Actual = V_{SENSE} x GAIN

Example: Gain = 100, For 100mV V_{SENSE} input we measure 10.1V. The overall accuracy (V_{OA}) is 1% as shown in Equation 3.

$$V_{OA} = 100 \times \left(\frac{10.1 - 10}{10}\right) = 1$$
percent (EQ. 3)

Power Dissipation

It is possible to exceed the $+150^{\circ}$ C maximum junction temperatures under certain load and power supply conditions. It is therefore important to calculate the maximum junction temperature (T_{JMAX}) for all applications to determine if power supply voltages, load conditions, or package type need to be modified to

12

remain in the safe operating area. These parameters are related using Equation 4:

$$T_{JMAX} = T_{MAX} + \theta_{JA} \times PD_{MAXTOTAL}$$
 (EQ. 4)

where:

- P_{DMAXTOTAL} is the sum of the maximum power dissipation of each amplifier in the package (PD_{MAX})
- PD_{MAX} for each amplifier can be calculated using Equation 5:

$$PD_{MAX} = V_{S} \times I_{qMAX} + (V_{S} - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_{L}}$$
(EQ.5)

where:

- T_{MAX} = Maximum ambient temperature
- θ_{JA} = Thermal resistance of the package
- PD_{MAX} = Maximum power dissipation of 1 amplifier
- V_{CC} = Total supply voltage
- I_{qMAX} = Maximum quiescent supply current of 1 amplifier
- V_{OUTMAX} = Maximum output voltage swing of the application

R_L = Load resistance

intersil

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest Rev.

DATE	REVISION	CHANGE
2/3/10	FN6973.1	-Page1: Edited last sentence of paragraph 2. Moved order of GAIN listings from 20, 50, 100 to 100, 50, 20 in the 3rd paragraph. Under Featuresremoved "Low Input Offset Voltage 250μV,max" Under Features moved order of parts listing from 20, 50, 100 (from top to bottom) to 100, 50, 20Page 3: Removed coming soon on ISL28005FH50Z and ISL28005FH20Z and changes the order or listing them to 100, 50, 20Page 5: VOA test. Under conditions columndeleted "20mV to". It now reads Vsense = 100mV SR test. Under conditions columndeleted what was there. It now reads Pulse on RS+pin, See Figure 15 -Page 6: ts test. Removed Gain = 100 and Gain = 100V/V in both description and conditions columns respectivelyPage 9 Added Figure 15 and adjusted figure numbers to account for the added figure.
12/14/09	FN6973.0	Initial Release

Products

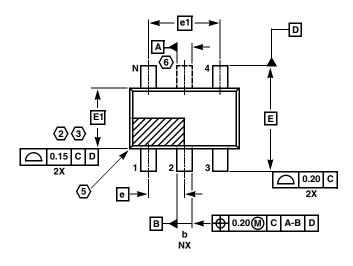
Intersil Corporation is a leader in the design and manufacture of high-performance analog semiconductors. The Company's products address some of the industry's fastest growing markets, such as, flat panel displays, cell phones, handheld products, and notebooks. Intersil's product families address power management and analog signal processing functions. Go to www.intersil.com/products for a complete list of Intersil product families.

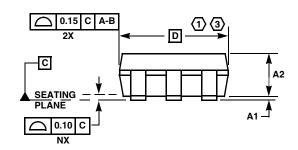
*For a complete listing of Applications, Related Documentation and Related Parts, please see the respective device information page on intersil.com: ISL28005

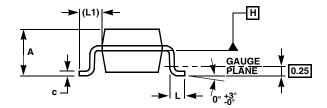
To report errors or suggestions for this datasheet, please go to www.intersil.com/askourstaff

FITs are available from our website at http://rel.intersil.com/reports/search.php

SOT-23 Package Family







MDP0038 SOT-23 PACKAGE FAMILY

	MILLIM			
SYMBOL	SOT23-5	SOT23-6	TOLERANCE	
Α	1.45	1.45	MAX	
A1	0.10	0.10	±0.05	
A2	1.14	1.14	±0.15	
b	0.40	0.40	±0.05	
С	0.14	0.14	±0.06	
D	2.90	2.90	Basic	
E	2.80	2.80	Basic	
E1	1.60	1.60	Basic	
е	0.95	0.95	Basic	
e1	1.90	1.90	Basic	
L	0.45	0.45	±0.10	
L1	0.60	0.60	Reference	
N	5	6	Reference	
D F 0/0				

Rev. F 2/07

NOTES:

- Plastic or metal protrusions of 0.25mm maximum per side are not included.
- Plastic interlead protrusions of 0.25mm maximum per side are not included.
- 3. This dimension is measured at Datum Plane "H".
- 4. Dimensioning and tolerancing per ASME Y14.5M-1994.
- Index area Pin #1 I.D. will be located within the indicated zone (SOT23-6 only).
- 6. SOT23-5 version has no center lead (shown as a dashed line).

For additional products, see www.intersil.com/product_tree

Intersil products are manufactured, assembled and tested utilizing ISO9000 quality systems as noted in the quality certifications found at www.intersil.com/design/quality

Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design, software and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see www.intersil.com

intersil